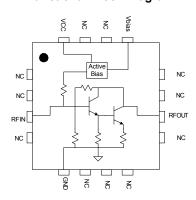


Product Description

Sirenza Microdevices' SGB-2433 is a high performance SiGe HBT MMIC amplifier utilizing a Darlington configuration with an active bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 3V to 5V supply the SGB-2433 does not require a drop resistor as compared to typical Darlington amplifiers. This robust amplifier features a Class 1C ESD rating. low thermal resistance. and unconditional stability. The SGB-2433 product is designed for high linearity 3V gain block applications that require small size and minimal external components. It is on chip matched to 50 ohm and an external bias inductor choke is required for the application band.

Functional Block Diagram



SGB-2433

DC - 4 GHz Active Bias Gain Block



Product Features

- High reliability SiGe HBT Technology
- **Robust Class 1C ESD**
- Simple and small size
- P1dB = 6.9 dBm @ 1950MHz
- IP3 = 18.0 dBm @ 1950MHz
- Low Thermal Resistance = 110 C/W

Applications

- 3V Battery operated applications
- LO buffer amp
- RF pre-driver and RF receive path

Key Specifications

| Symbol | Parameters: Test Conditions $Z_0 = 50\Omega$, $V_{CC} = 3.0V$, Ic = 25mA, T = 30°C) | Unit | Min. | Тур. | Max. |
|----------------------|---|------|------|------|------|
| f _O | Frequency of Operation | MHz | DC | | 4000 |
| | Small Signal Gain – 850MHz | | | 19.1 | |
| S ₂₁ | Small Signal Gain – 1950MHz | dB | 15.7 | 17.2 | 18.7 |
| | Small Signal Gain – 2400MHz | | | 16.2 | |
| | Output Power at 1dB Compression – 850MHz | | | 7.7 | |
| P _{1dB} | Output Power at 1dB Compression – 1950MHz | dBm | 5.4 | 6.9 | |
| | Output Power at 1dB Compression – 2400MHz | | | 6.2 | |
| | Output IP3 – 850MHz | | | 19.5 | |
| OIP3 | Output IP3 – 1950MHz | dB | 16.0 | 18.0 | |
| | Output IP3 – 2400MHz | | | 18.0 | |
| IRL | Input Return Loss @ 1950MHz | dB | 10 | 13.4 | |
| ORL | Output Return Loss @ 1950MHz | dB | 10 | 13.6 | |
| lc | Current | mA | 21 | 25 | 29 |
| NF | Noise Figure @1950MHz | dB | | 3.5 | 4.5 |
| R _{th, j-l} | Thermal Resistance (junction - lead) | °C/W | | 110 | |

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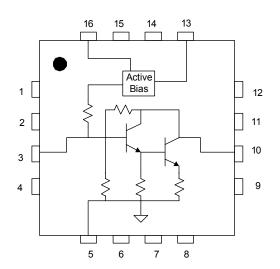
Detailed Performance Table: Vcc=3V, Ic=25mA, T=25C, Z=50ohms

| Symbol | Parameter | Units | 100MHz | 500MHz | 850MHz | 1950MHz | 2400MHz | 3500MHz |
|--------|----------------------------------|-------|--------|--------|--------|---------|---------|---------|
| G | Small Signal Gain | dB | 19.7 | 19.5 | 19.1 | 17.2 | 16.2 | 14.0 |
| OIP3 | Output 3rd Order Intercept Point | dBm | | 20.0 | 19.5 | 18.0 | 18.0 | |
| P1dB | Output Power at 1dB Compression | dBm | | 8.3 | 7.7 | 6.9 | 6.2 | |
| IRL | Input Return Loss | dB | 25.0 | 19.9 | 17.1 | 13.4 | 12.7 | 10.5 |
| ORL | Output Return Loss | dB | 20.5 | 18.9 | 17.1 | 13.6 | 13.1 | 13.0 |
| S12 | Reverse Isolation | dB | 22.4 | 22.6 | 22.9 | 23.7 | 23.9 | 24.5 |
| NF | Noise Figure | dB | 3.8 | 3.2 | 3.2 | 3.5 | 3.9 | 4.3 |

Pin Out Description

| ı III Out | Description | |
|------------------------------|-------------|---|
| Pin# | Function | Description |
| 1,2,4,6, 7,8,11, 12,14 | NC | These are no connect pins. Leave them unconnected on the PC board. |
| 3 | RFIN | RF input pin. A DC voltage should not be connected externally to this pin |
| 5 | GND | An extra ground pin that is connected to the backside exposed paddle. Connection is optional. |
| 10 | RFOUT | RF Output pin. Bias is applied to the Darlington stage thru this pin. |
| 13 | VBIAS | This pin sources the current from the active bias circuit. Connect to pin 10 thru an inductor choke. |
| 16 | VCC | This is Vcc for the active bias circuit. |
| Back- side | GND | The backside exposed paddle is the main electrical GND and requires multiple vias in the PC board to GND. It is also the main thermal path. |

Simplified Device Schematic



Absolute Maximum Ratings

| Parameters | Value | Unit |
|--|-------------|------|
| Current (Ic total) | 60 | mA |
| Device Voltage (V _D) | 5 | V |
| Power Dissipation | 0.2 | W |
| Operating Lead Temperature (T _L) | -40 to +85 | °C |
| RF Input Power | 20 | dBm |
| Storage Temperature Range | -40 to +150 | °C |
| Operating Junction Temperature (T _J) | +150 | °C |

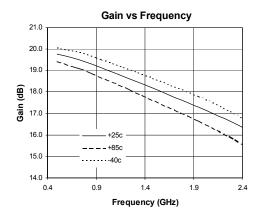
Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation the device voltage and current must not exceed the maximum operating values specified in the table on page one.

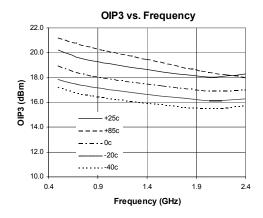
Bias conditions should also satisfy the following expression: $I_DV_D < (T_J - T_L) \, / \, R_{TH^+} \, j\text{-}I$

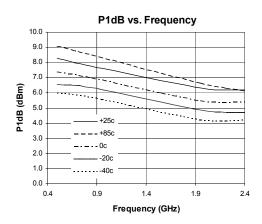


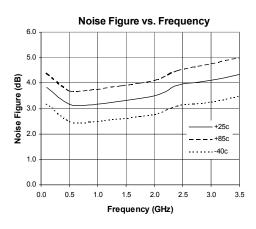


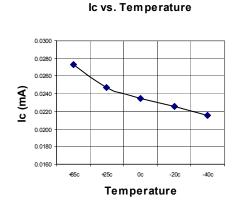
Evaluation Board Data (Vcc= V_{BIAS} = 3.0V, I_c = 25mA) Bias Tee substituted for DC feed inductor (L1)

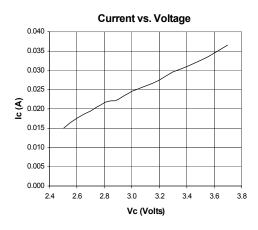








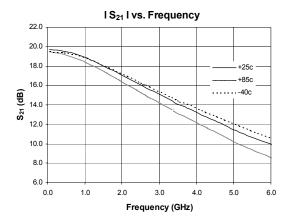


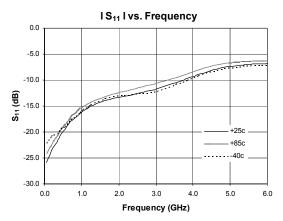


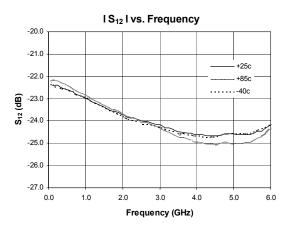


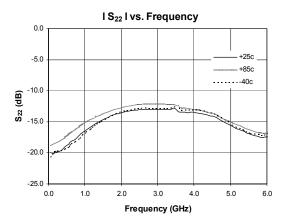


Evaluation Board Data (Vcc= V_{BIAS} = 3.0V, I_c = 25mA) Bias Tee substituted for DC feed inductor (L1)



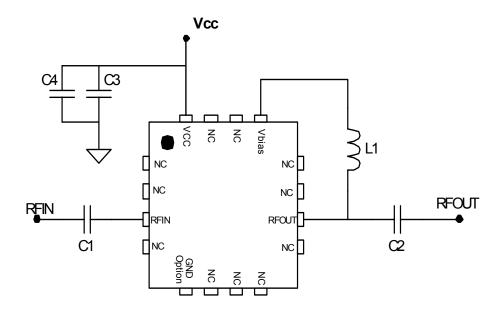




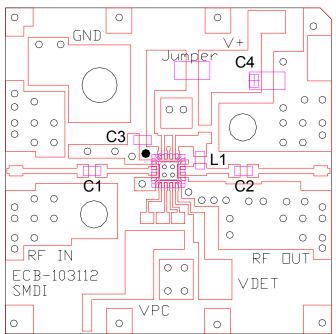




Typical Evaluation Board Schematic for 3.0V



Evaluation Board - Board material GETEK, 31mil thick, Dk=4.2, 1 oz. copper



Component Values By Band

| Designator | 500MHz | 850MHz | 1950MHz | 2400MHz |
|------------|--------|--------|---------|---------|
| C3 | 1000pF | 1000pF | 1000pF | 1000pF |
| C4* | 1uF | 1uF | 1uF | 1uF |
| C1, C2 | 220pF | 68pF | 43pF | 22pF |
| L1 | 68 nH | 33nH | 22nH | 18nH |

^{*} C4 is optional depending on application and filtering. Not required for SGB device operation.

Note: The amplifier can be run from a 5V supply by simply inserting a 82 ohm resistor in series with Vcc.



Preliminary Data Sheet

SGB-2433 DC-4GHz Active Bias Gain Block

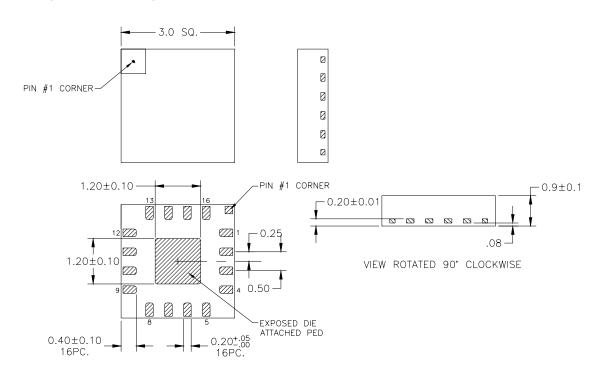
Part Marking

The part will be symbolized with an "SGB-2433" marking designator on the top surface of the package.

| Part Number Ordering Inform | mation |
|-----------------------------|--------|
|-----------------------------|--------|

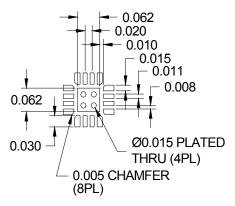
| Part Number | Reel Size | Devices/Reel | |
|-------------|-----------|--------------|--|
| SGB-2433 | 13" | 3000 | |

Package Outline Drawing (Dimensions in mm)



Recommended Land Pattern:

DIMENSIONS IN INCHES





Caution: ESD Sensitive

Appropriate precaution in handling, packaging and testing devices must be observed.

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